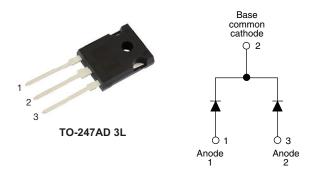
VS-C4PU3006L-N3

Vishay Semiconductors

www.vishay.com

Ultrafast Soft Recovery Diode, 2 x 15 A FRED Pt[®] Gen 4



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 15 A					
V _R	600 V					
V _F at I _F	1.12 V					
t _{rr} typ.	See Recovery table					
T _J max.	175 °C					
Package	TO-247AD 3L					
Circuit configuration	Common cathode					

FEATURES

- Gen 4 FRED Pt[®] technology
- Low I_{RRM} and reverse recovery charge
- · Very low forward voltage drop
- · Polyimide passivated chip for high reliability standard
- 175 °C operating junction temperature
- Designed and gualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

Gen 4 Fred technology, state of the art, ultralow V_F, soft switching optimized for Discontinuous (Critical) Mode (DCM) and IGBT F/W diode.

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS				
Peak repetitive reverse voltage	V _{RRM}		600	V				
Average rectified forward current	I _{F(AV)}	T _C = 146 °C	15	٨				
Non-repetitive peak surge current, per leg	I _{FSM}	T_{C} = 25 °C, t_{p} = 8.3 ms, half sine wave	200	A				
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C				

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-			
		I _F = 15 A	-	1.32	1.55			
	V _F	I _F = 30 A	-	1.53	-	- - - -		
		I _F = 15 A, T _J = 125 °C	-	1.17	-			
Forward voltage		I _F = 30 A, T _J = 125 °C	-	1.42	-			
		I _F = 15 A, T _J = 150 °C	-	1.12	1.28			
		I _F = 30 A, T _J = 150 °C	-	1.38	-			
Reverse leakage current	I _R	$V_{R} = V_{R}$ rated	-	-	15			
neverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA		
Junction capacitance	CT	V _R = 600 V	-	16	-	pF		

Revision: 19-Feb-2019 Document Number: 95934 1 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000





DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST C	MIN.	TYP.	MAX.	UNITS		
Reverse recovery time	+	T _J = 25 °C	I _F = 15 A dI _F /dt = 1000 A/μs V _R = 400 V	-	60	-	ns	
Reverse recovery time	t _{rr}	T _J = 125 °C		-	83	-		
Doold roooyand ourrant	I _{RRM}	T _J = 25 °C		-	13	-	^	
Peak recovery current		T _J = 125 °C		-	21	-	A	
	0	T _J = 25 °C		-	500	-	50	
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	1100	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction to case	R _{thJC}		-	-	1.4			
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	40	°C/W		
Thermal resistance, case to heat sink	R _{thCS}		-	0.4	-			
Weight			-	6.0	-	g		
Weight			-	0.21	-	oz.		
Mounting torque			6.0 (5)	-	12 (10)	kgf · cm (lbf · in)		
Marking device		Case style TO-247AD 3L	C4PU3006L					

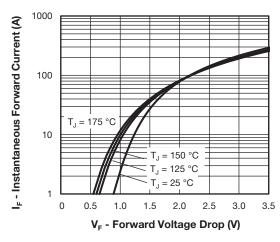


Fig. 1 - Typical Forward Voltage Drop Characteristics

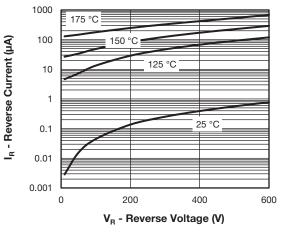


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



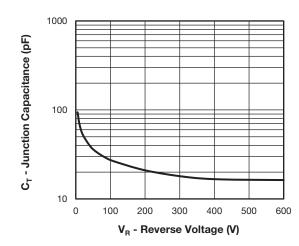


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

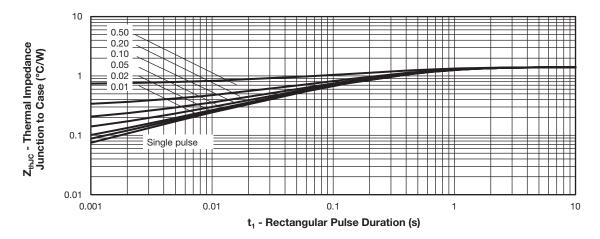
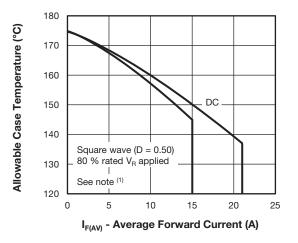
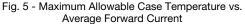


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



www.vishay.com



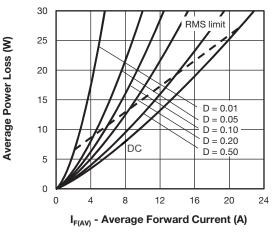


Fig. 6 - Forward Power Loss Characteristics

Note

Revision: 19-Feb-2019

3

Document Number: 95934

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

 $^{^{(1)} \}mbox{ Formula used: } T_C = T_J - (P_d + P_{dREV}) \ x \ R_{thJC}; \\ Pd = \mbox{ forward power loss = } I_{F(AV)} \ x \ V_{FM} \ at \ (I_{F(AV)}/D) \ (see \ Fig.5)$

 P_{dREV} = inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_R = rated V_R



VS-C4PU3006L-N3

Vishay Semiconductors

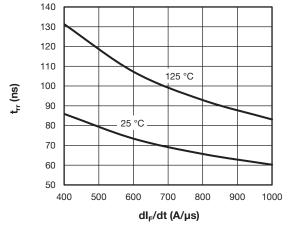


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

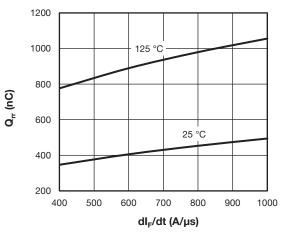


Fig. 8 - Typical Stored Charge vs. dl_F/dt

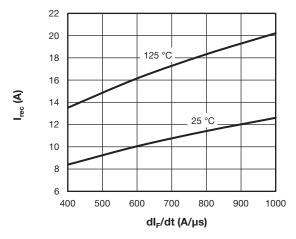


Fig. 9 - Typical Reverse Current vs. dl_F/dt



ORDERING INFORMATION TABLE

Device code	VS-	с	4	Р	U	30	06	L	-N3
	1	2	3	4	5	6	7	8	9
	 Vishay Semiconductors product Circuit configuration: C = common diode 								
 G = common diode FRED Pt Gen 4 P = TO-247 package Process type: U = ultrafast recovery 									
	6 - 7 - 8 - 9 -	Volt Pac Env	age rati kage: L ironmer	ng (30 = ng (06 = = long l tal digit: en-free,	= 600 V) ead		nt, and	totally l	ead (Pb

ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-C4PU3006L-N3	25	500	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95626					
Part marking information	www.vishay.com/doc?95007				



TO-247AD 3L

DIMENSIONS in millimeters and inches



View B

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
с	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

(2, 52, 51) (4) Section C - C, D - D, E - E

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	5.46 BSC		5 BSC	
ØК	0.2	0.254		0.010	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØР	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51	BSC	0.217	' BSC	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

- ⁽³⁾ Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- ⁽⁵⁾ Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- ⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

 Revision: 06-Mar-2020
 1
 Document Number: 95626

 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
 DiodesEurope@vishay.com

 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2025 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED

Revision: 01-Jan-2025

1